



深圳市奥伦德科技股份有限公司

Shenzhen Orient Tech Ltd . Co ., Ltd

MOC302X

产品规格书

Specification Sheet

品 名(P/N): 光电耦合器 Photocoupler

客户名称(Customer): _____

本厂型号(Mfg P/N): MOC302X

日 期(Date): _____

Add: Block A 3rd Floor No.4 Building Tian An Cyber Park Huang Ge Rd, Long Gang Dist, Shenzhen, Guangdong, 518172

Web: www.orient-opto.com



1. 特点(Features)

- (1) 绝缘电压: (Isolation voltage between input and output) $V_{iso} \geq 5,000\text{Vrms}$
- (2) 6脚可控硅光电隔离器 (6pin DIP optoisolators, triac driver output)
- (3) 符合欧盟 REACH 标准 (Compliance with EU REACH)
- (4). 产品符合 RoHS 要求 (The product itself will remain within RoHS compliant version)
- (5). 运行温度范围: (Operating temperature) -40 °C to +100 °C

2. 说明 (description)

描述该系列器件包含一个红外发光二极管和光电探测器。不含卤素和 Sb_2O_3 .

3. 应用范围 (Application Range)

- | | |
|-----------------------------|----------------------------------|
| •交流电动机驱动 (AC Motor Drives) | •交流电机启动器 (AC Motor Starters) |
| •照明控制 (Lighting Controls) | •电磁阀控制 (Solenoid/Valve Controls) |
| •固态继电器 (Solid State Relays) | •温度控制器 (Temperature Controls) |

4. 最大绝对额定值(常温 T=25°C) Max Absolute rated Value (Normal Temperature=25°C)

参数 Parameter		符号 Symbol	典型值 Rated Value	单位 Unit
输入 Input	正向电流 (Forward Current)	I_F	50	mA
	结温 (Junction Temperature)	T_J	125	°C
	逆向电压 (Reverse Voltage)	V_R	6	V
	功率耗损 (Power Dissipation)	P	100	mW
输出 Output	断态重复峰值电压 (Off-State Output Terminal Voltage)	V_{DRM}	400	V
	峰值重复浪涌电流 Peak Repetitive Surge Current (PW=1ms, 120 pps)	I_{TSM}	1	A
	结温 (Junction Temperature)	T_J	125	°C
	集电极功率耗损 (Collector Power Dissipation)	P_C	300	mW
总功率消耗 (Total Power Dissipation)		P_{tot}	330	mW
*1 绝缘电压 (Insulation Voltage)		V_{iso}	5000	Vrms
工作温度 (Working Temperature)		T_{opr}	-40 ~ + 100	°C
存贮温度 (Deposit Temperature)		T_{stg}	-55 ~ + 150	
*2 焊锡温度 (Soldering Temperature)		T_{sol}	260	

*1. 交流测试, 时间 1 分钟, R.H. =40~60% AC Test, 1 minute, humidity = 40~60%

如下是绝缘测试的方法. Insulation test method as below:

- (1) 将产品的两端短路。 Short circuit both terminals of photocoupler
- (2) 测试绝缘电压时无电流通过。 No Current when testing insulation voltage
- (3) 测试时加正弦波形电压。 Adding sine wave voltage when testing

*2. 锡焊时间为 10 秒 soldering time is 10 seconds



5. 光电特性(常温 T=25°C) (Opto-electronic Characteristics)

参数 Parameter		符号 Symbol	条件 Condition	最小 Min	典型值 Typ.*	最大 Max	单位 Unit
输入 (Input)	正向电压 (Forward Voltage)	V _F	I _F =20mA	---	1.2	1.6	V
	逆向电流(Reverse Current)	I _R	V _R =6V	---	0.05	10	μA
输出 (Output)	1.峰值阻断电流, 任一方向 (Peak Blocking Current, Either Direction)	I _{DRM}	V _{DRM} = 400V	---	10	100	nA
	峰值状态电压, 任一方向 (Peak On-State Voltage, Either Direction)	V _{TM}	I _{TM} =100mA Peak	---	1.7	3.0	V
	2.断态电压临界上升率 (Critical rate of Rise of Off-State Voltage)	dv/dt	V _{in} =240Vrms	1000	---	---	V/us
组合 Couple	3.LED 触发电流, 锁存输出所需的电流, 任一方向 (Led Trigger Current,Current Required to Latch Output, Either Direction)	MOC3020	I _{FT} Main Terminal Voltage = 3V	---	---	30	mA
		MOC3021		---	---	15	
		MOC3022		---	---	10	
		MOC3023		---	---	5	
	Holding Current, Either Direction	I _H		---	200	---	uA

*1. Test voltage must be applied within dv/dt rating.

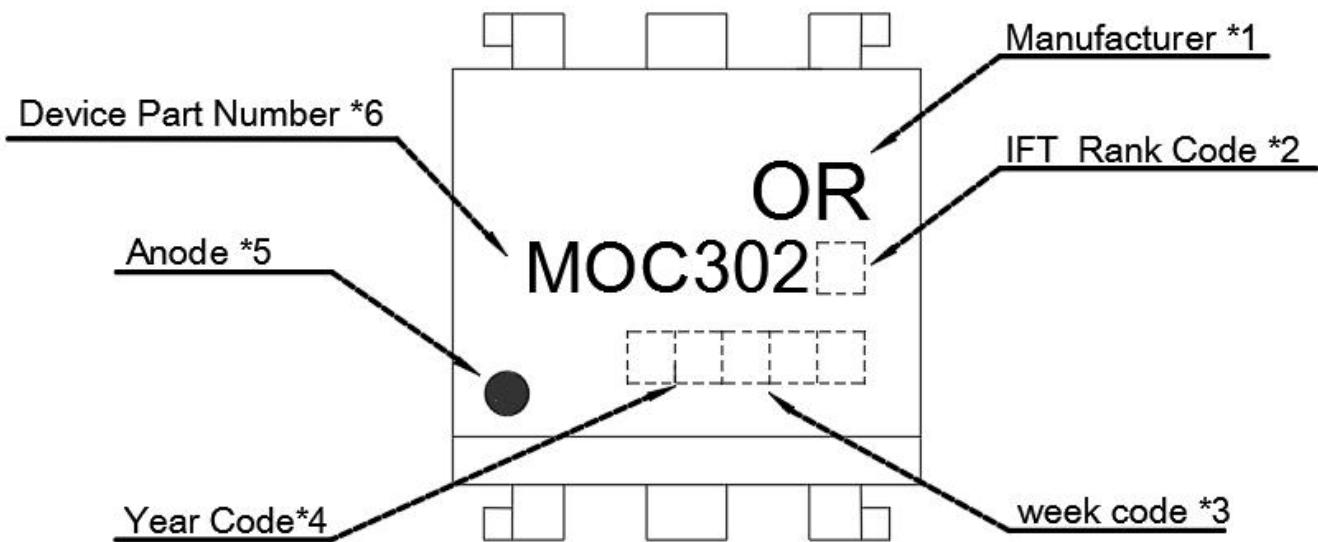
*2. This is static dv/dt. Commutating dv/dt is a function of the load-driving thyristor(s) only.

*3. All devices are guaranteed to trigger at an I_F value less than or equal to max I_{FT}.

Therefore, recommended operating I_F lies between max I_{FT}, 30 mA for MOC3020, 15 mA for MOC3021, 10 mA for MOC3022, 5 mA for MOC3023, and absolute max I_F (50mA).



6. 命名规则 (Naming Rule)

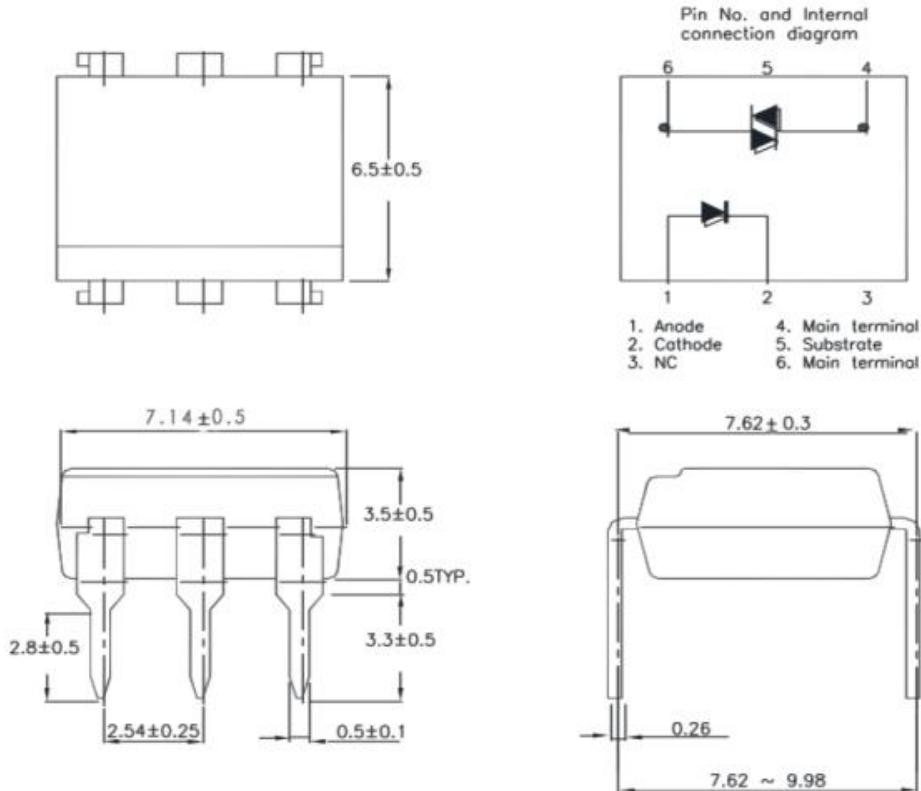


注:

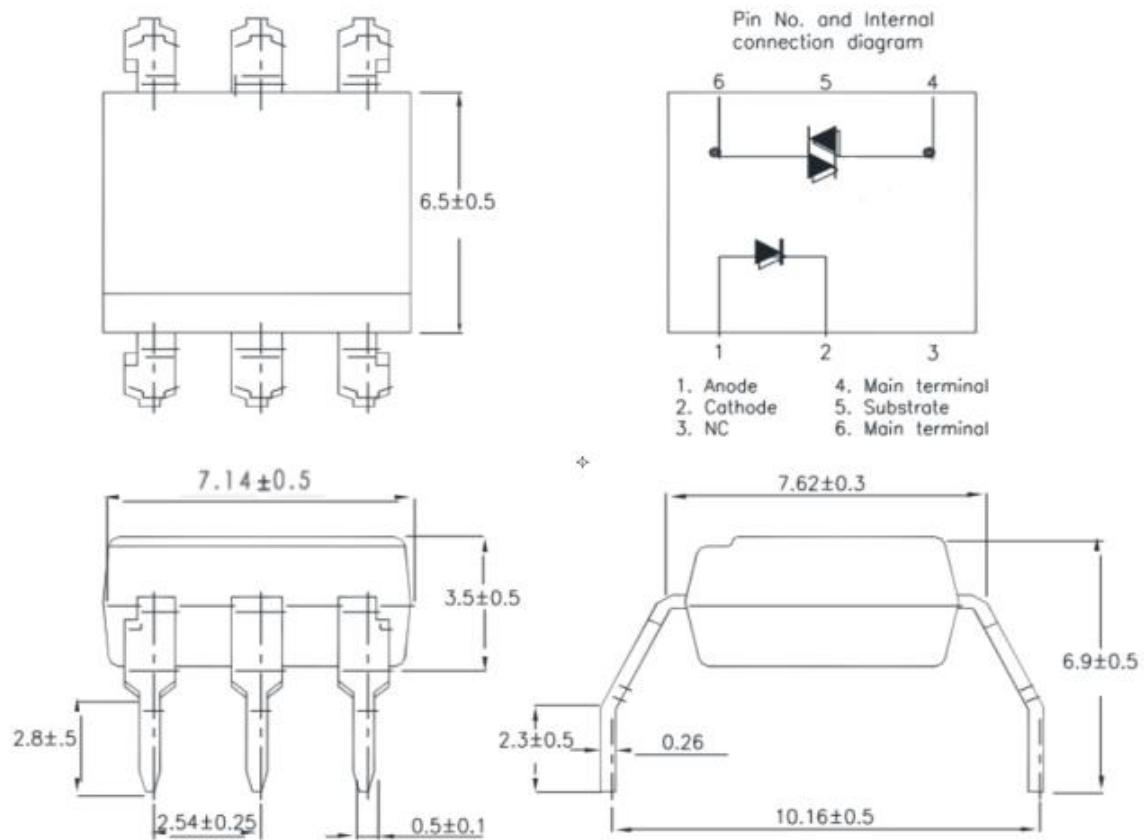
- (1) 制造商名称: OR代表制造商 Shenzhen Orient Components Co., Ltd.
- (2) 等级代码IF Rank Code: 等级代码 Rank: 有0、1、2、3共4种形式, X=0代表MOC3020; X=1代表MOC3021; X=2代表MOC3022; X=3代表MOC3023。
- (3) 周代码:Week Code: 01代表第一周、02代表第二周、依此类推。
- (4) 年代码:Year Code: 例如: F8 或C8, 其中F表铁支架/C表铜支架, 8代表2018年、依此类推。
- (5) Anode: 代表正极。
- (6) Device Part Number 代表MOC302X光耦产品.

7. 外形尺寸 (Outer Dimension)

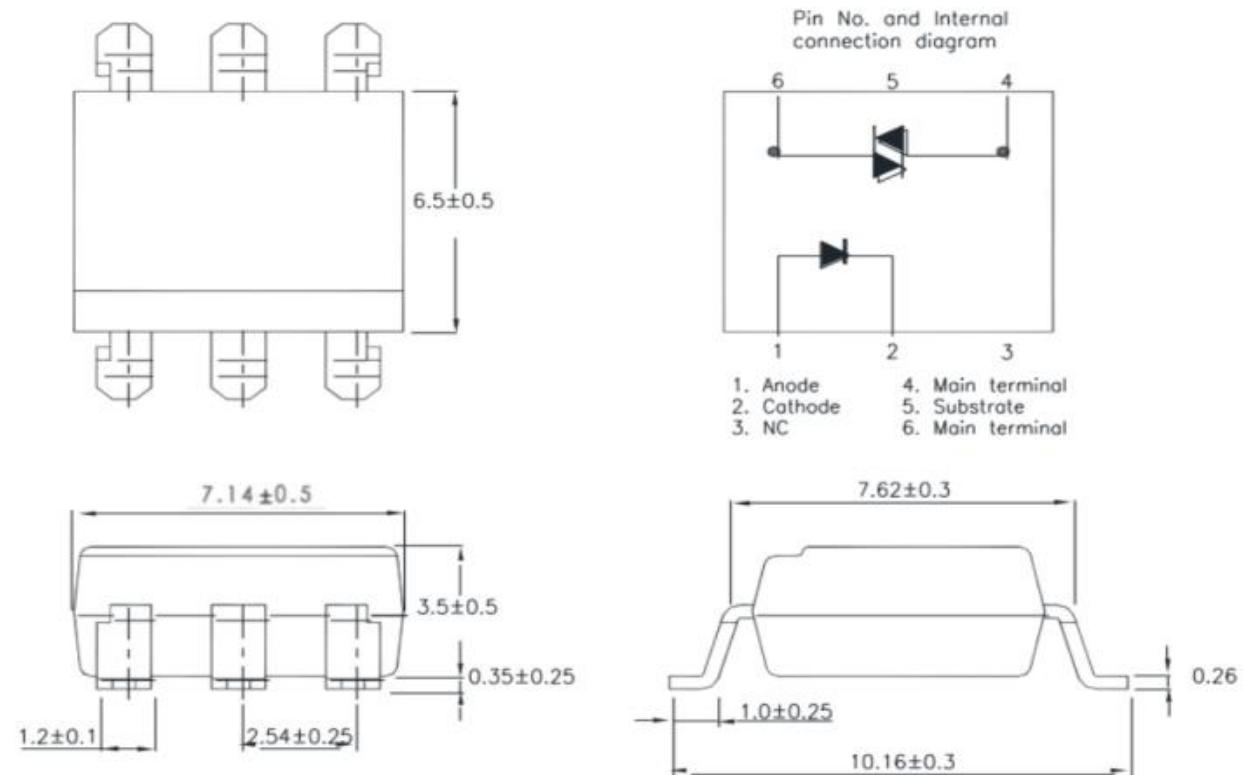
(1).MOC302X



(2).MOC302XM

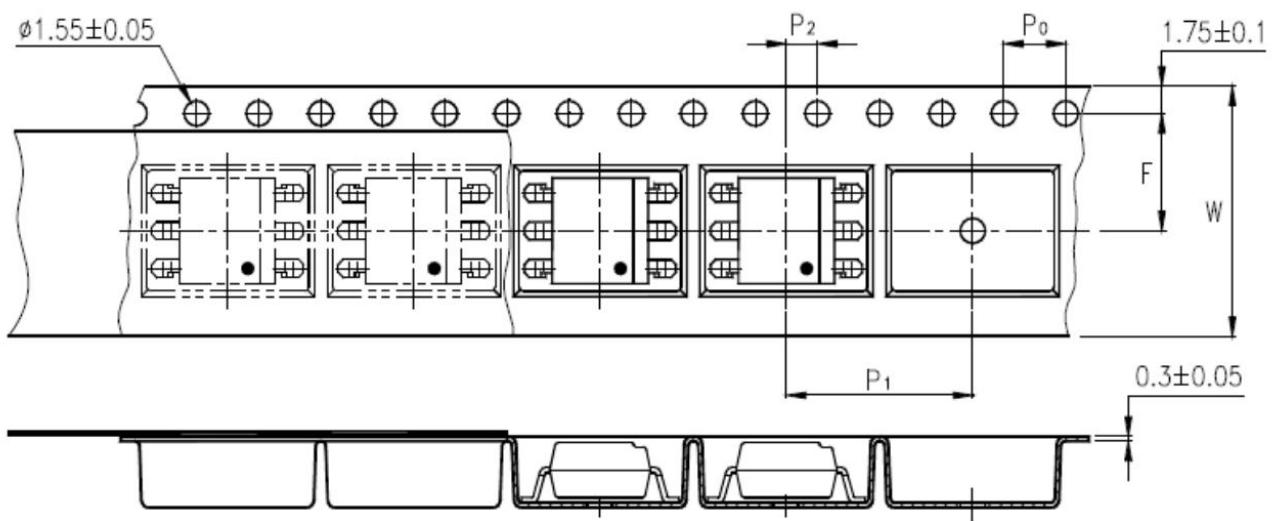


(3) . MOC302XS



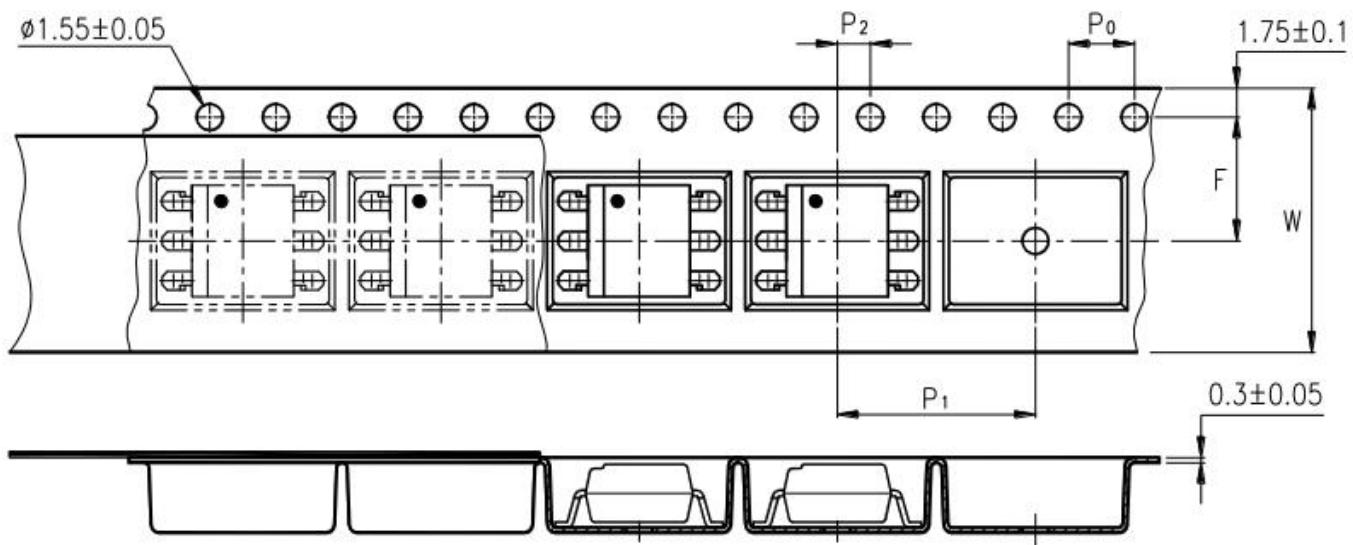
8. 编带尺寸 (Taping Dimensions)

(1). MOC302XS-TA





(2). MOC302XS-TA1



Description	Symbol	Dimension in mm (inch)
Tape wide	W	16±0.3 (0.63)
Pitch of sprocket holes	P ₀	4±0.1 (0.15)
Distance of compartment	F	7.5±0.1 (0.295)
	P ₂	2±0.1 (0.079)
Distance of compartment to compartment	P ₁	12±0.1 (0.472)

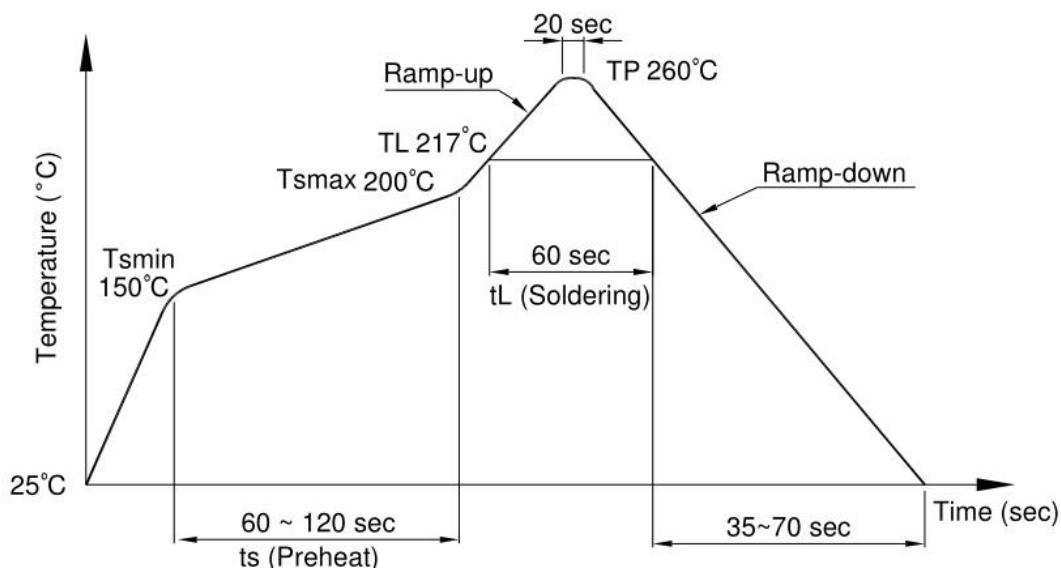
封装类型	MOC302XS series(TA/TA1)
数量(个)	1000

9. 焊接温度曲线 (Temperature Profile Of Soldering)

(1). 红外回流焊 (jedec-std-020c 兼容) (IR Reflow soldering (JEDEC-STD-020C compliant))

注意：一次焊接回流建议在温度和时间配置文件如下所示的条件下。不要焊接超过三次。

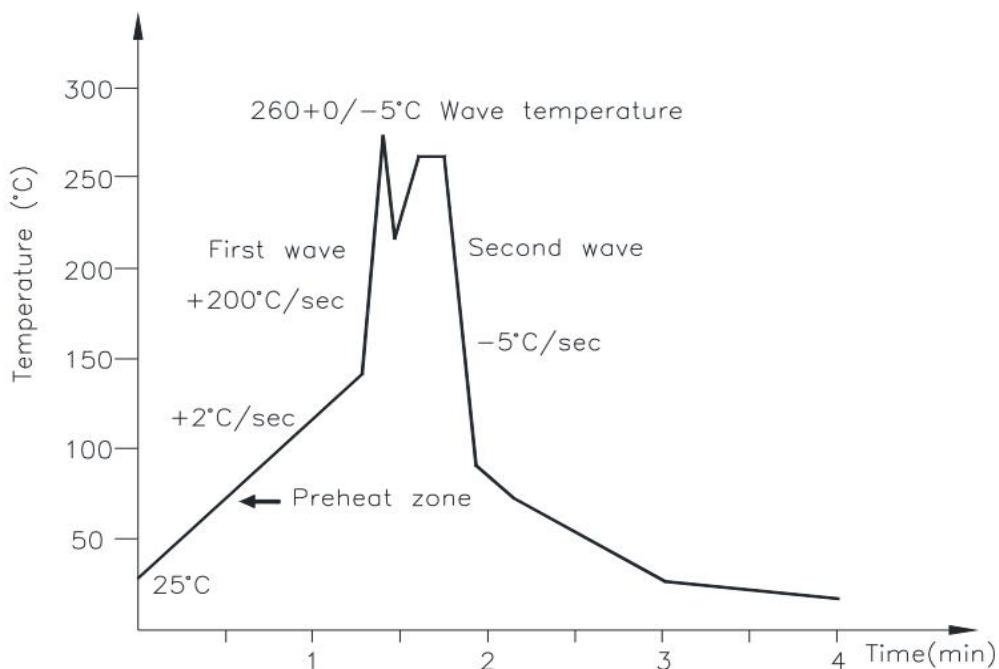
配置项	条件
预热 (Preheat)	
-最低温度 (TSmin)	150°C
-最高温度 (TSmax)	200°C
-时间 (最小到最大 (TS))	90±30 sec
焊接区 (Soldering zone)	
-温度 (TL)	217°C
-时间 (tL)	60 sec
峰值温度 (Peak Temperature)	260°C
爬升率 (Ramp-up rate)	3°C / sec max.
下降率 (3°C / sec max.)	3~6°C / sec



(2).波峰焊接 (jedec22a111 兼容) (Wave soldering (JEDEC22A111 compliant))

建议在温度条件下一次性焊接。

温度 (Temperature)	260+0/-5°C
时间 (Time)	10 sec
预热温度 (Preheat temperature)	5 to 140°C
预热时间 (Preheat time)	30 to 80 sec



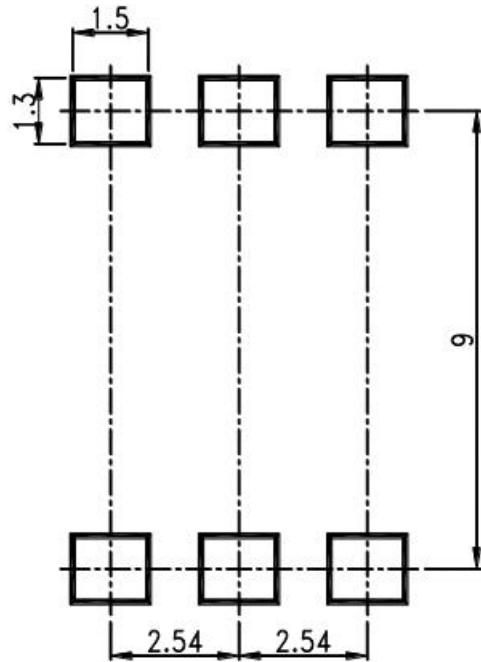
(3).电烙铁手工焊接 (Hand soldering by soldering iron)

允许单铅焊接在每一个过程中, 建议一次性焊接。

温度 (Temperature)	380+0/-5°C
时间 (Time)	3 sec max

10. 推荐的焊盘 (RECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD))

Unit: mm



11. 特性曲线 (Characteristics Curve)

Fig.1 Forward Current vs.

Ambient Temperature

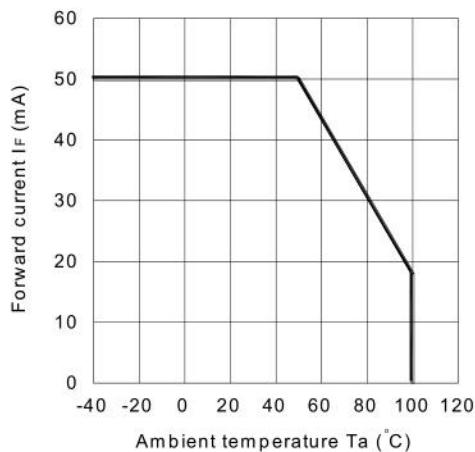


Fig.2 On-state Current vs. Ambient

Temperature

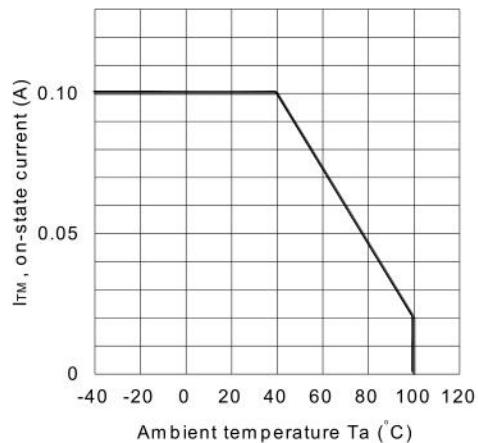


Fig.3 Minimum Trigger Current
vs. Ambient Temperature

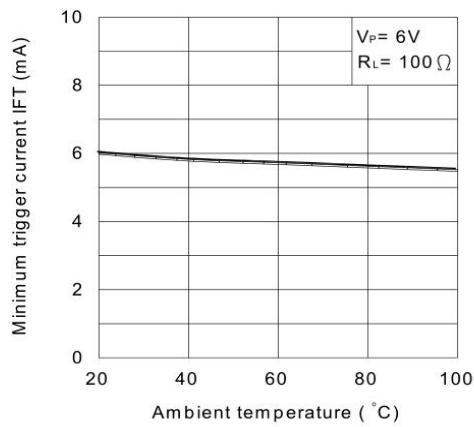


Fig.4 Forward Current vs. Forward
Voltage

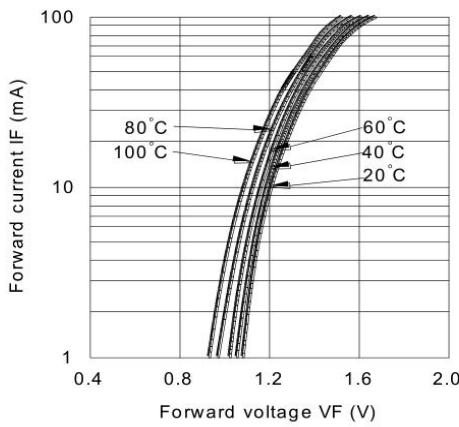


Fig.5 On-state Voltage vs. Ambient
Temperature

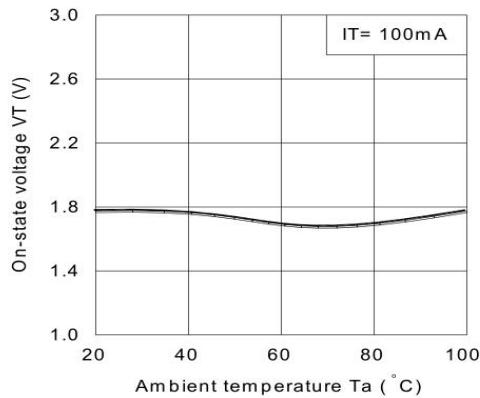


Fig.6 Holding Current vs.
Ambient Temperature

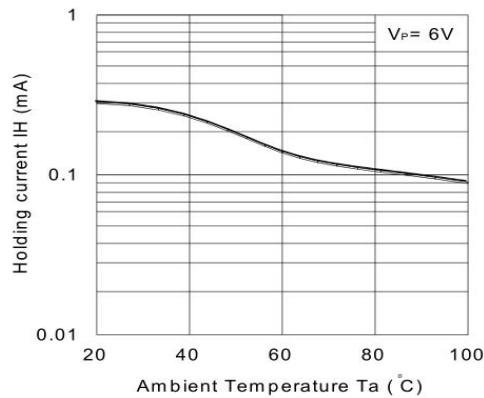


Fig.7 Repetitive Peak Off-state Current vs. Temperature

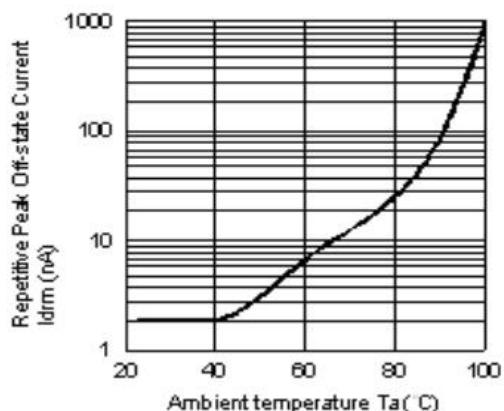
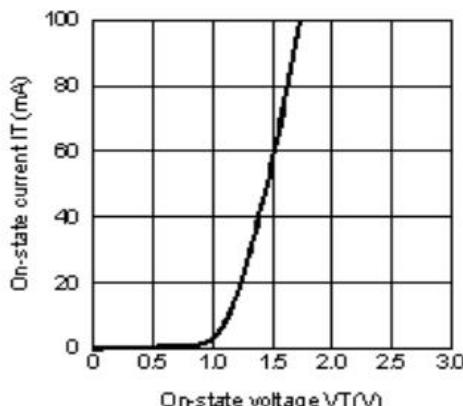


Fig.8 On-state Current vs. On-state Voltage



Basic Operation Circuit
Medium/High Power Triac Drive Circuit

